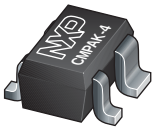


BFG325W/XR

NPN 14 GHz wideband transistor

Rev. 2 — 15 September 2011 Product data sheet

1. Product profile

1.1 General description

NPN silicon planar epitaxial transistor in a 4-pin dual-emitter SOT343R plastic package.

1.2 Features and benefits

- High power gain
- Low noise figure
- High transition frequency
- Gold metallization ensures excellent reliability

1.3 Applications

- Intended for Radio Frequency (RF) front end applications in the GHz range, such as:
  - analog and digital cellular telephones
  - cordless telephones (Cordless Telephone (CT), Personal Communication Network (PCN), Digital Enhanced Cordless Telecommunications (DECT), etc.)
  - radar detectors
  - pagers
  - Satellite Antenna TeleVision (SATV) tuners

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-	15	V
V_{CEO}	collector-emitter voltage	open base		-	-	6	V
I_C	collector current (DC)			-	-	35	mA
P_{tot}	total power dissipation	$T_{sp} \leq 90$ °C	[1]	-	-	210	mW
h_{FE}	DC current gain	I_C = 15 mA; V_{CE} = 3 V; T_j = 25 °C		60	100	200	
C_{CBS}	collector-base capacitance	V_{CB} = 5 V; f = 1 MHz; emitter grounded		-	0.27	0.4	pF
f_T	transition frequency	I_C = 15 mA; V_{CE} = 3 V; f = 1 GHz; T_{amb} = 25 °C		-	14	-	GHz

Table 1. Quick reference data *...continued*

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_{max}	maximum power gain[2]	I_C = 15 mA; V_{CE} = 3 V; f = 1.8 GHz; T_{amb} = 25 °C	-	18.3	-	dB
$\|s_{21}\|^2$	insertion power gain	I_C = 15 mA; V_{CE} = 3 V; f = 1.8 GHz; T_{amb} = 25 °C; $Z_S = Z_L$ = 50 Ω	-	14	-	dB
NF	noise figure	$\Gamma_s = \Gamma_{opt}$; I_C = 3 mA; V_{CE} = 3 V; f = 2 GHz	-	1.1	-	dB

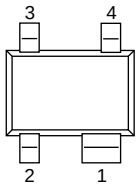
[1] T_{sp} is the temperature at the soldering point of the collector pin.

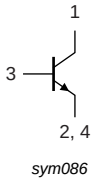
[2] G_{max} is the maximum power gain, if K > 1. If K < 1 then G_{max} = MSG, see Figure 4.

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Symbol
1	collector		
2	emitter		
3	base		
4	emitter		





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3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BFG325W/XR	-	plastic surface mounted package; reverse pinning; 4 leads	SOT343R

4. Marking

Table 4. Marking codes

Type number	Marking code[1]
BFG325W/XR	A8*

[1] * = p: made in Hong Kong.

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	15	V
V_{CEO}	collector-emitter voltage	open base		-	6	V
V_{EBO}	emitter-base voltage	open collector		-	2	V
I_C	collector current (DC)			-	35	mA
P_{tot}	total power dissipation	$T_{sp} \leq 90$ °C	[1]	-	210	mW
T_{stg}	storage temperature			–65	+175	°C
T_j	junction temperature			-	175	°C

[1] T_{sp} is the temperature at the soldering point of the collector pin.

6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Typ	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	$T_{sp} \leq 90$ °C	[1]	403	K/W

[1] T_{sp} is the temperature at the soldering point of the collector pin.

7. Characteristics

Table 7. Characteristics

T_j = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I_{CBO}	collector-base cut-off current	$I_E = 0$ A; $V_{CB} = 5$ V	-	-	15	nA
h_{FE}	DC current gain	$I_C = 15$ mA; $V_{CE} = 3$ V	60	100	200	
C_{CBS}	collector-base capacitance	$V_{CB} = 5$ V; f = 1 MHz; emitter grounded	-	0.27	0.4	pF
C_{CES}	collector-emitter capacitance	$V_{CE} = 5$ V; f = 1 MHz; base grounded	-	0.22	-	pF
C_{EBS}	emitter-base capacitance	$V_{EB} = 0.5$ V; f = 1 MHz; collector grounded	-	0.49	-	pF
f_T	transition frequency	$I_C = 15$ mA; $V_{CE} = 3$ V; f = 1 GHz; $T_{amb} = 25$ °C	-	14	-	GHz
G_{max}	maximum power gain[1]	$I_C = 15$ mA; $V_{CE} = 3$ V; f = 1.8 GHz; $T_{amb} = 25$ °C	-	18.3	-	dB
$\lvert s_{21}\rvert^2$	insertion power gain	$I_C = 15$ mA; $V_{CE} = 3$ V; $T_{amb} = 25$ °C; $Z_S = Z_L = 50\ \Omega$				
		f = 1.8 GHz	-	14	-	dB
		f = 3 GHz	-	10	-	dB
NF	noise figure	$\Gamma_s = \Gamma_{opt}$; $I_C = 3$ mA; $V_{CE} = 3$ V; f = 2 GHz	-	1.1	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression	$I_C = 15$ mA; $V_{CE} = 3$ V; f = 1.8 GHz; $T_{amb} = 25$ °C; $Z_S = Z_L = 50\ \Omega$	-	8.7	-	dBm
IP3	third order intercept point	$I_C = 15$ mA; $V_{CE} = 3$ V; f = 1.8 GHz; $T_{amb} = 25$ °C; $Z_S = Z_L = 50\ \Omega$	-	19.4	-	dBm

[1] G_{max} is the maximum power gain, if K > 1. If K < 1 then G_{max} = MSG, see Figure 4.

K is the Rollet stability factor: $K = \frac{1 + |Ds|^2 - |s_{11}|^2 - |s_{22}|^2}{2 \times |s_{21}| \times |s_{12}|}$ where $Ds = s_{11} \times s_{22} - s_{12} \times s_{21}$.

MSG = maximum stable gain.

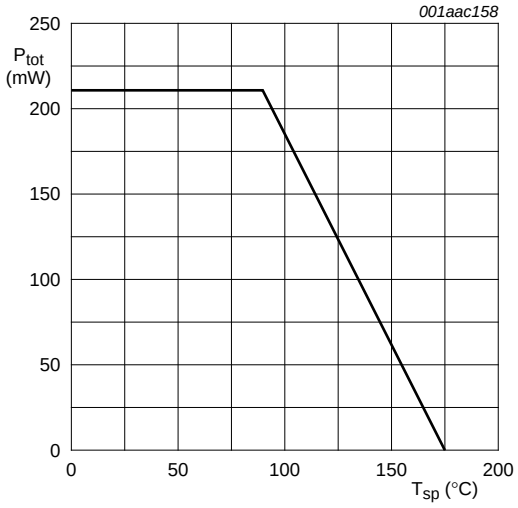


Fig 1. Power derating curve

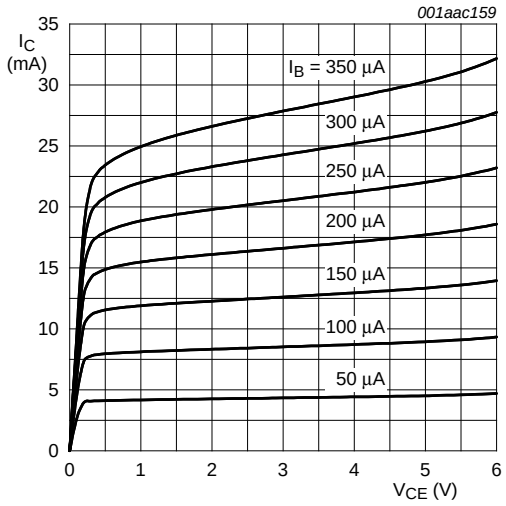
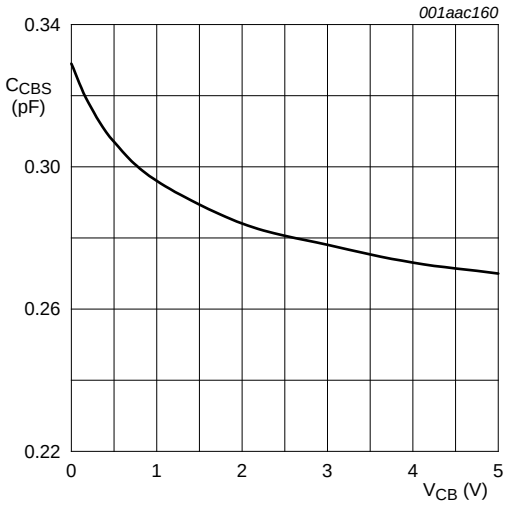
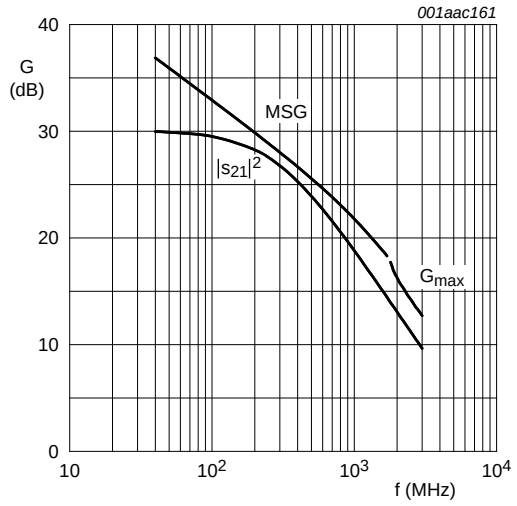


Fig 2. Collector current as a function of collector-emitter voltage; typical values



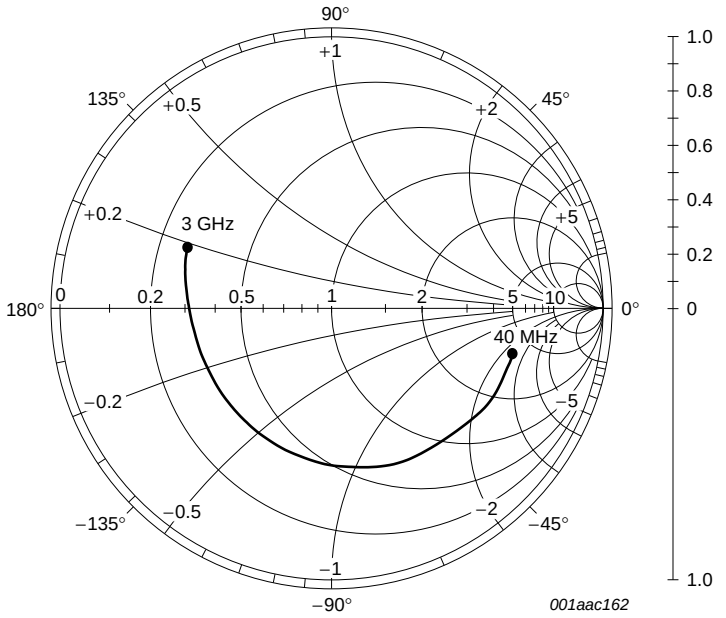
I_C = 0 mA; f = 1 MHz.

Fig 3. Collector-base capacitance as a function of collector-base voltage; typical values



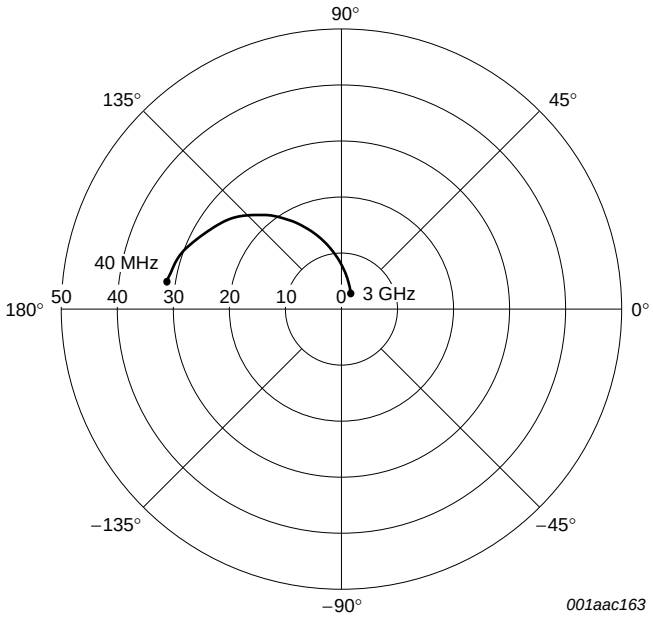
I_C = 15 mA; V_{CE} = 3 V.

Fig 4. Gain as a function of frequency; typical values



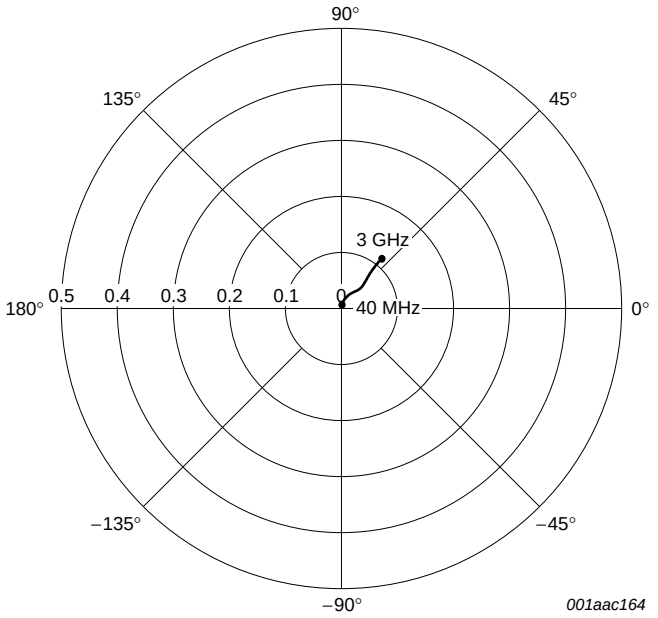
V_{CE} = 3 V; I_C = 15 mA; Z_o = 50 Ω.

Fig 5. Common emitter input reflection coefficient (s_{11}); typical values



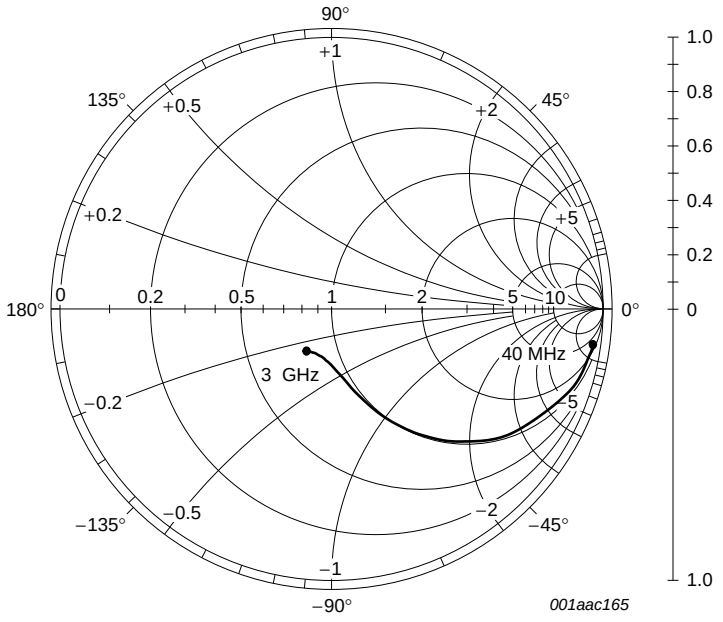
V_{CE} = 3 V; I_C = 15 mA.

Fig 6. Common emitter forward transmission coefficient (s_{21}); typical values



V_{CE} = 3 V; I_C = 15 mA.

Fig 7. Common emitter reverse transmission coefficient (s_{12}); typical values



V_{CE} = 3 V; I_C = 15 mA; Z_o = 50 Ω.

Fig 8. Common emitter output reflection coefficient (s_{22}); typical values

8. Application information

Table 8. SPICE parameters of the BFG325 DIE

Sequence	Parameter	Value	Unit
1	IS	26.6	aA
2	BF	200	-
3	NF	1	-
4	VAF	40	V
5	IKF	105	mA
6	ISE	2.3	fA
7	NE	2.114	-
8	BR	10	-
9	NR	1	-
10	VAR	2.5	V
11	IKR	10	A
12	ISC	0	aA
13	NC	1.5	-
14	RB	3.6	Ω
15	RE	1.5	Ω
16	RC	2.6	Ω
17	CJE	185.6	fF
18	VJE	890	mV
19	MJE	0.294	-
20	CJC	77.06	fF
21	VJC	601	mV
22	MJC	0.159	-
23	XCJC	1	-
24	FC	0.7	-
25	TF	8.1	ps
26	XTF	10	-
27	VTF	1000	V
28	ITF	150	mA
29	PTF	0	deg
30	TR	0	ns
31	KF	0	-
32	AF	1	-
33	TNOM	25	°C
34	EG	1.014	eV
35	XTB	0	-
36	XTI	8	-
37	Q1.AREA	2.5	-

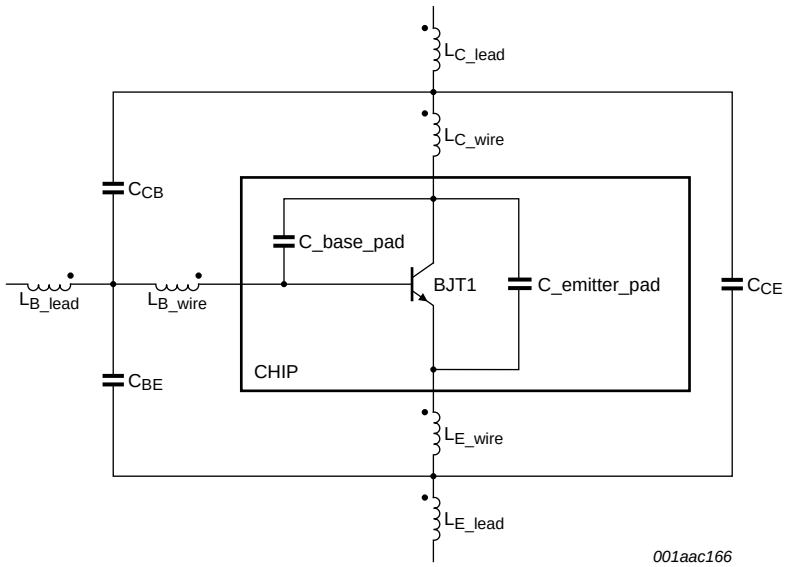


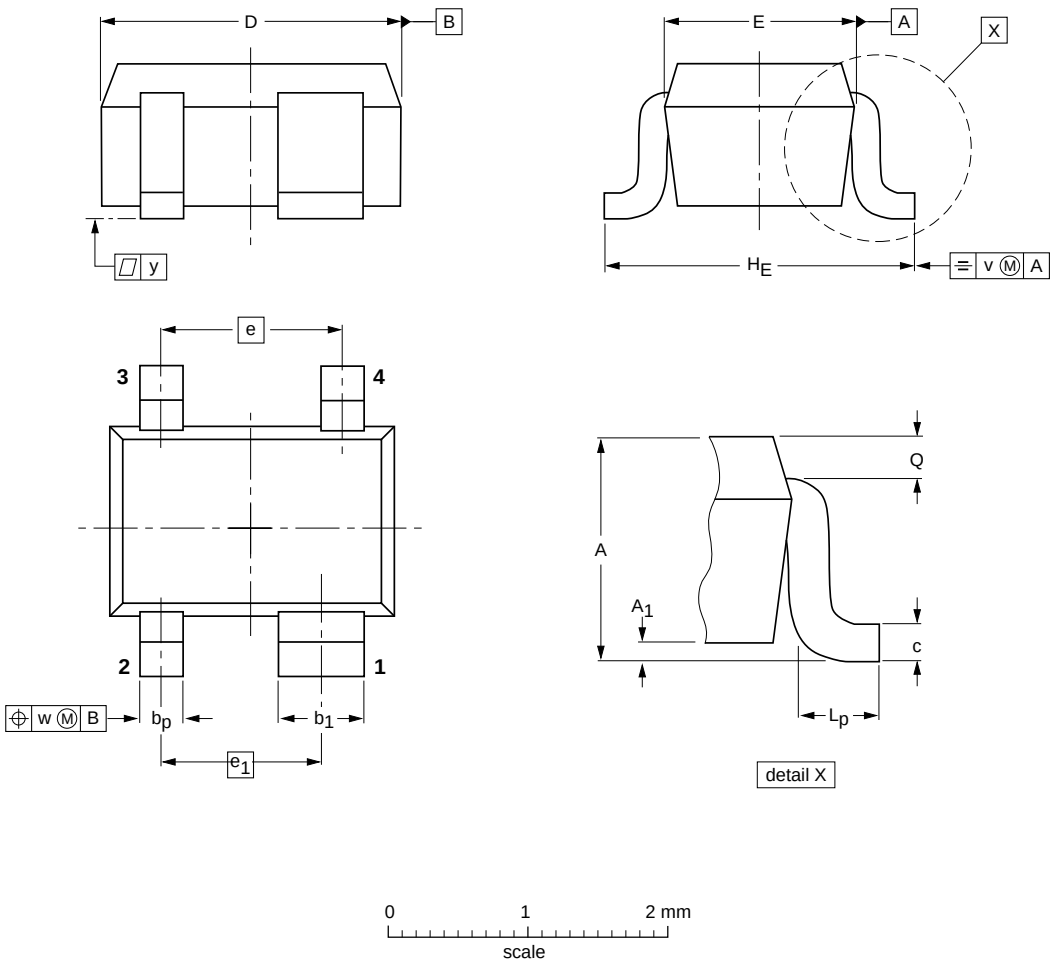
Fig 9. Package equivalent circuit of SOT343R

Table 9. List of components; see Figure 9

Designation	Value	Unit
C_{CB}	2	fF
C_{BE}	80	fF
C_{CE}	80	fF
C_base_pad	67	fF
C_emitter_pad	142	fF
L_{C_wire}	0.767	nH
L_{B_wire}	0.842	nH
L_{E_wire}	0.212	nH
L_{C_lead}	0.28	nH
L_{B_lead}	0.281	nH
L_{E_lead}	0.1	nH

9. Package outline

Plastic surface-mounted package; reverse pinning; 4 leads **SOT343R**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	b_1	c	D	E	e	e_1	H_E	L_p	Q	v	w	y
mm	1.1 0.8	0.1	0.4 0.3	0.7 0.5	0.25 0.10	2.2 1.8	1.35 1.15	1.3	1.15	2.2 2.0	0.45 0.15	0.23 0.13	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT343R						~~97-05-21~~ 06-03-16

Fig 10. Package outline SOT343R

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFG325W_XR v.2	20110915	Product data sheet	-	BFG325W_XR v.1
Modifications:	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Package outline drawings have been updated to the latest version.			
BFG325W_XR v.1 (9397 750 14246)	20050202	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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12. Contact information

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For sales office addresses, please send an email to: **salesaddresses@nxp.com**

13. Contents

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